

MECHANICAL DATA

Weight: approx. 10.3 mg Packaging codes/options:

GS18/10K per 13" reel (8 mm tape), 10K/box GS08/3K per 7" reel (8 mm tape), 15K/box

Case: SOD-123

Vishay Semiconductors

Small Signal Fast Switching Diode

FEATURES

- Silicon epitaxial planar diode
- · Fast switching diode
- This diode is also available in other case styles including the DO-35 case with the type designation 1N4448, the MiniMELF case with the type designation LL4448, and the with the type designation IMBD444
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

case with the	RoHS
SOT-23 case	
8	

e3

PARTS TABLE					
PART	ORDERING CODE	TYPE MARKING	INTERNAL CONSTRUCTION	REMARKS	
1N4448W-V	1N4448W-V-GS18 or 1N4448W-V-GS08	A3	Single diode	Tape and reel	

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V _R	75	V	
Repetitive peak reverse voltage		V _{RRM}	100	V	
Average rectified current half wave rectification with resistive load ⁽¹⁾	f ≥ 50 Hz	I _{F(AV)}	150	mA	
Surge current	$t < 1 \text{ s and } T_j = 25 ^\circ\text{C}$	I _{FSM}	500	mA	
Power dissipation ⁽¹⁾		P _{tot}	500	mW	

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Thermal resistance junction to ambient air ⁽¹⁾		R _{thJA}	350	K/W
Junction temperature		Тj	150	°C
Storage temperature		T _{stg}	- 65 to + 150	°C

Note

⁽¹⁾ Valid provided that leads at a distance of 8 mm from case are kept at ambient temperature.

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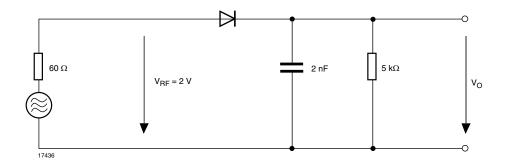
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1N4448W-V

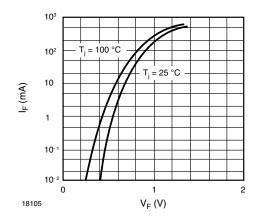


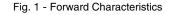
ELECTRICAL CHARACTERISTICS ($T_{amb} = 25 \text{ °C}$, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 5 mA	V _F	0.62		0.72	V
	I _F = 100 mA	VF			1	V
Leakage current	V _R = 20 V	I _R			25	nA
	V _R = 75 V	I _R			5	μA
	$V_R = 20 \text{ V}, \text{ T}_J = 150 ^\circ\text{C}$	I _R			50	μA
Capacitance	$V_F = V_R = 0 V$				4	pF
Reverse recovery time	$I_F = 10 \text{ mA}, i_R = 1 \text{ mA}, \\ V_R = 6 \text{ V}, \text{ R}_L = 100 \Omega$	t _{rr}			4	ns
Rectification efficiency	f = 100 MHz, V _{RF} = 2 V	ην	0.45			

RECTIFICATION EFFICIENCY MEASUREMENT CIRCUIT



TYPICAL CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)





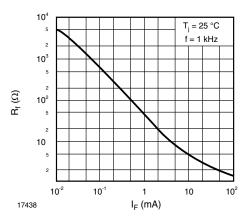
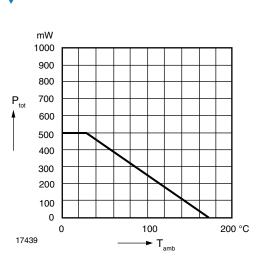


Fig. 2 - Dynamic Forward Resistance vs. Forward Current

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Fig. 3 - Admissible Power Dissipation vs. Ambient Temperature

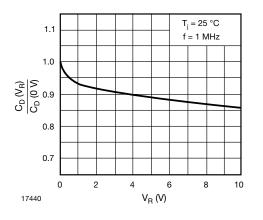


Fig. 4 - Relative Capacitance vs. Reverse Voltage

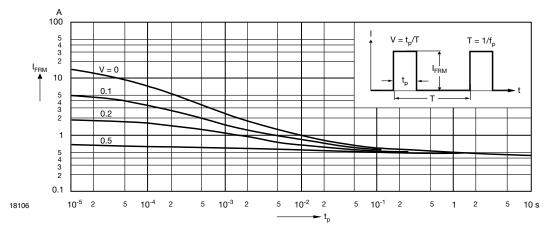


Fig. 6 - Admissible Repetitive Peak Forward Current vs. Pulse Duration

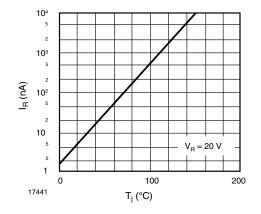


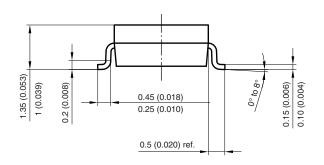
Fig. 5 - Leakage Current vs. Junction Temperature

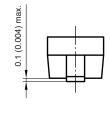
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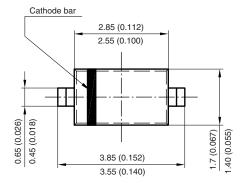


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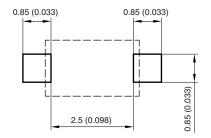
PACKAGE DIMENSIONS in millimeters (inches): SOD-123







Mounting Pad Layout



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